L5300GJ

5 V low drop voltage regulator

Features

Max DC supply voltage	V_S	40 V
Max output voltage tolerance	ΔV_0	+/-2%
Max dropout voltage	V_{dp}	500 mV
Output current	I_0	300 mA
Quiescent current	I_{qn}	5 µA(1) 55 µA(2)

1. Typical value with regulator disabled.
2. Typical value with regulator enabled.

- Operating DC supply voltage range 5.6 V to 40 V
- Low dropout voltage
- 300 mA current capability
- Low quiescent current
- Very low consumption mode
- Precision output voltage 5 V +/- 2%
- Reset circuit sensing the output voltage
- Programmable reset pulse delay with external capacitor
- Early warning
- Very wide stability range with low value output capacitor
- Thermal shutdown and short circuit protection
- Wide temperature range (T_j = -40 °C to 150 °C)
- Enable input for enabling / disabling the voltage regulator

PowerSSO-12

Description

L5300GJ is a low dropout linear regulator with microprocessor control functions such as power on reset, low voltage reset, early warning, ON/OFF control. Typical quiescent current is 55 µA in very low output current mode and enabled regulator. It drops to 5 µA with not enabled regulator.

On-chip trimming results in high output voltage accuracy (2%). Accuracy is kept over wide temperature range, line and load variation. Early warning circuit monitors the input voltage and compares it with an internal voltage reference.

The maximum input voltage is 40 V. The maximum output current is internally limited.

Internal temperature protection disables the voltage regulator output. In addition, only low value ceramic capacitor on output is required for stability (equal or above 220 nF).

Table 1. Device summary

Package	Order codes	
	Tube	Tape and reel
PowerSSO-12	L5300GJ	L5300GJTR

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1 Block diagram and pins description

Figure 1. Block diagram

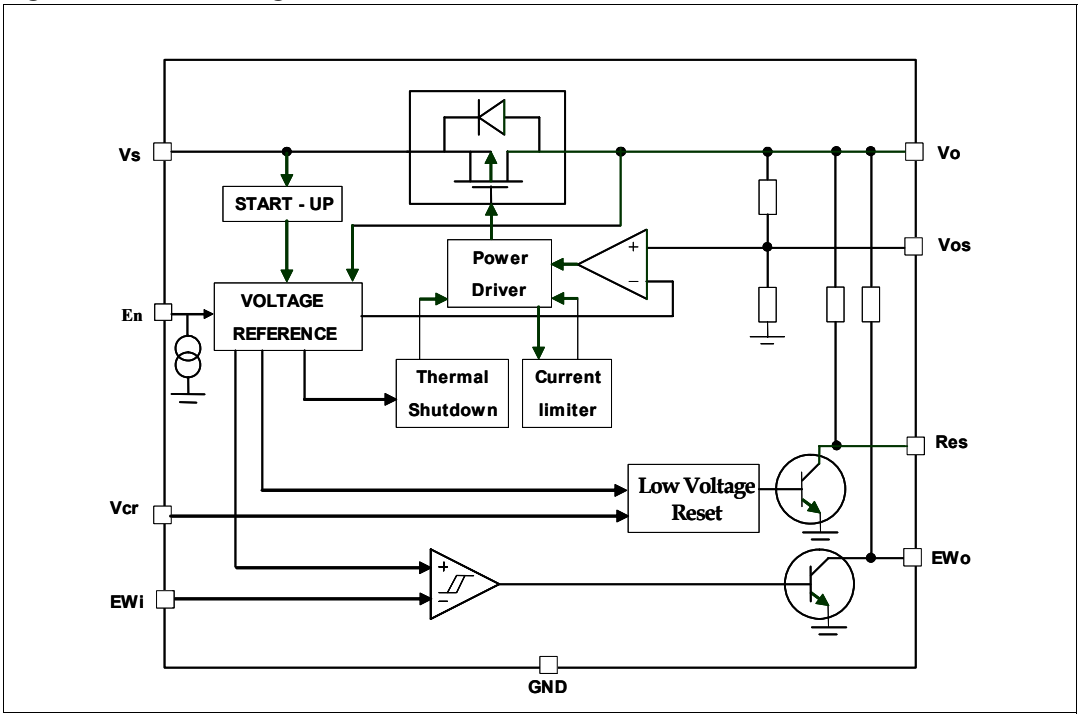


Figure 2. Configuration diagram (top view)

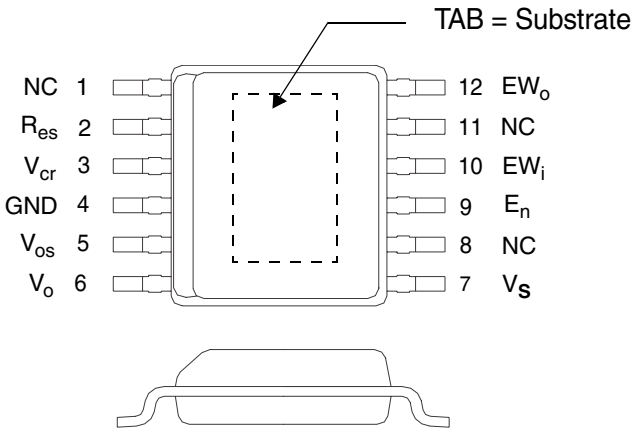


Table 2. Pins description

N°	Name	Function
1	NC	Not connected
2	R_{es}	Reset output. Internally connected to V_o through a 20 KΩ pull up resistor. This pin is pulled low when $V_o < V_{o\_th}$. Keep open if not needed
3	V_{cr}	Reset delay. Connect an external capacitor between V_{cr} pin and ground to adjust the reset delay time. Keep open if not needed
4	GND	Ground reference
5	V_{os}	Regulator output voltage sensing (connect to V_o)
6	V_o	5 V regulated output. Block to GND with a ceramic capacitor ($C_o \geq 220$ nF for regulator stability)
7	V_S	Supply voltage, block directly to GND on the IC with a capacitor
8	NC	Not connected
9	E_n	Enable input. A high signal switches the regulator ON. Connect to V_S if not needed
10	EW_i	Early warning input. This pin monitors the V_S voltage level through a resistor divider. Connect to V_S if not needed
11	NC	Not connected
12	EW_o	Early warning output. Internally connected to V_o through 20 KΩ pull up resistor. This pin is pulled low when EW_i is below bandgap reference voltage. Keep open if not needed
-	TAB	TAB is connected to the substrate of the chip: connect to GND or leave open (see *Figure 2*).

2 Electrical specifications

2.1 Absolute maximum ratings

Stressing the device above the rating listed in the *Table 3: Absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{sdc}	DC supply voltage	-0.3 to 40	V
I_{Vsdc}	Input current	Internally limited	
V_{odc}	DC output voltage	-0.3 to 6	V
I_{Vodc}	DC output current	Internally limited	
$V_{od\ Res}$	Open drain output voltage R_{es}	-0.3 to V_{odc} + 0.3	V
$I_{od\ Res}$	Open drain output current R_{es}	Internally limited	
$V_{od\ EWo}$	Open drain output voltage EW_o	-0.3 to V_{odc} + 0.3	V
$I_{od\ EWo}$	Open drain output current EW_o	Internally limited	
V_{cr}	V_{cr} voltage	-0.3 to V_o + 0.3	V
V_{EWi}	Early warning input voltage	-0.3 to 40	V
V_{En}	Enable input	-0.3 to 40	V
T_j	Junction temperature	-40 to 150	°C
$V_{ESD\ HBM}$	ESD HBM voltage level (HBM-MIL STD 883C)	+/- 2	kV
$V_{ESD\ CDM}$	ESD CDM voltage level (CDM AEC-Q100-011)	+/- 750	V

2.2 Thermal data

Table 4. Thermal data (1)

Symbol	Parameter	Value	Unit
$R_{thj\text{-}case}$	Thermal resistance junction to case: PowerSSO-12	8	°K/W
$R_{thj\text{-}amb}$	Thermal resistance junction to ambient: PowerSSO-12	48	°K/W

1. The values quoted are for PCB 77mm x 86 mm x 1.6mm, FR4, double layer with thermal vias (one copper heatsink layer, thickness 0.070 mm, area 8 cm^2).

2.3 Electrical characteristics

Values specified in this section are for V_S = 5.6 V to 31 V, T_j = -40°C to 150°C unless otherwise stated.

Table 5. General

Pin	Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_o	V_{o_ref}	Output voltage	V_S = 8 V to 18 V; I_o = 8 mA to 300 mA	4.9	5.0	5.1	V
V_o	V_{o_ref}	Output voltage	V_S = 5.6 V to 31V; I_o = 8 mA to 300 mA	4.85	5.0	5.15	V
V_o	V_{o_ref}	Output voltage	V_S = 5.6 V to 31 V; I_o = 0.1 mA to 8 mA	4.75	5.0	5.25	V
V_o	I_{short}	Short circuit current	V_S = 13.5 V	0.8	1.8	2.6	A
V_o	I_{lim}	Output current capability(1)	V_S = 13.5 V	0.6	1.6	2.5	A
V_S, V_o	V_{line}	Line regulation voltage	V_S = 6 V to 28 V; I_o = 60 mA			40	mV
V_o	V_{load}	Load regulation voltage	V_S = 13.5 V; I_o = 8 mA to 300 mA; T_j = 25 °C			40	mV
			V_S = 8 V to 18 V; I_o = 8 mA to 300 mA			55	
V_S, V_o	V_{dp}	Drop voltage (2)	I_o = 300 mA			500	mV
V_S, V_o	SVR	Ripple rejection	f_r = 100 Hz (3)		60		dB
V_o	I_{oth_H}	Normal consumption mode output current		8			mA
V_o	I_{oth_L}	Very low consumption mode output current				1.1	mA
V_o	I_{oth_Hyst}	Output current switching threshold hysteresis	V_S = 13.5 V; T_j = 25 °C		0.8		mA
V_S, V_o	I_{qs}	Current consumption with regulator disabled $I_{qs} = I_{Vs} - I_o$	V_S = 13.5 V; E_n = low		5	10	µA
V_S, V_o	I_{qn_1}	Current consumption with regulator enabled $I_{qn\_1} = I_{Vs} - I_o$	V_S = 13.5 V; I_o = 0.1 mA to 1mA; E_n = high		55	80	µA
V_S, V_o	I_{qn_300}	Current consumption with regulator enabled $I_{qn\_300} = I_{Vs} - I_o$	V_S = 13.5 V; I_o = 300 mA; E_n = high		3	4.2	mA
	T_w	Thermal protection temperature		150		190	°C
	T_{w_hy}	Thermal protection temperature hysteresis			10		°C

1. Measured output current when the output voltage has dropped 100 mV from its nominal value obtained at 13.5 V and I_o = 75 mA.

2. V_S - V_o measured dropout when the output voltage has dropped 100 mV from its nominal value obtained at 13.5V and I_o = 75 mA.
3. Guaranteed by design.

Table 6. Reset

Pin	Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
R_{es}	V_{Res_l}	Reset output low voltage	R_{ext} = 5 kΩ; V_o > 1 V			0.4	V
R_{es}	I_{Res_lkg}	Reset output high leakage current	$V_{Res} = V_{out}$			1	µA
R_{es}	R_{res}	Pull-up internal resistance	Versus V_o	10	20	40	kΩ
R_{es}	V_{o_th}	V_o out of regulation threshold	V_o decreasing	6	8	10	%below V_{o_ref}
V_{cr}	V_{Rlth}	Reset timing low threshold	V_S = 13.5 V	15	18	22	% V_{o_ref}
V_{cr}	V_{Rhth}	Reset timing high threshold	V_S = 13.5 V	47	50	53	% V_{o_ref}
V_{cr}	I_{cr}	Charge current	V_S = 13.5 V	10	20	30	µA
V_{cr}	I_{dr}	Discharge current	V_S = 13.5 V	10	20	30	µA
R_{es}	T_{rr}	Reset reaction time				2	µs
R_{es}	T_{rd}	Reset delay time	V_S = 13.5 V; C_{tr} = 1 nF	2	4	6	ms

Table 7. Early warning

Pin	Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
EW_i	$E_{wi\_th\_low}$	EW input low threshold voltage		2.35	2.50	2.65	V
EW_i	$E_{wi\_th\_high}$	EW input high threshold voltage		2.42	2.57	2.72	V
EW_i	$E_{wi\_th\_hyst}$	EW input threshold hysteresis			70		mV
EW_i	I_{EWi_lkg}	EW input leakage current	V_{EWi} = 0 V; V_S > 3 V	-1		1	µA
EW_o	R_{EWo}	Pull-up internal resistance	Versus V_o	10	20	40	kΩ
EW_o	E_{Wo_lv}	EW output low voltage (with external pull up)	V_{EWi} < 2.35 V; V_S > 4 V; R_{ext} = 5 kΩ			400	mV
EW_o	I_{Wo}	EW output leakage	V_{EWo} = 5 V			1	µA

Table 8. Enable

Pin	Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
E_n	V_{En_low}	E_n input low voltage				1	V
E_n	V_{En_high}	E_n input high voltage		3			V

Table 8. Enable (continued)

Pin	Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
E_n	V_{En_hyst}	E_n input hysteresis			500		mV
E_n	$I_{\_leak}$	Pull-down current	V_{En} = 5 V		3	10	µA

2.4 Electrical characteristics curves

Figure 3. Output voltage vs T_j

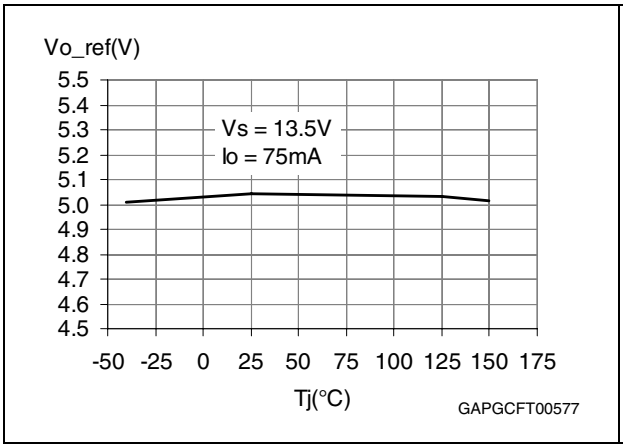


Figure 4. Output voltage vs V_S

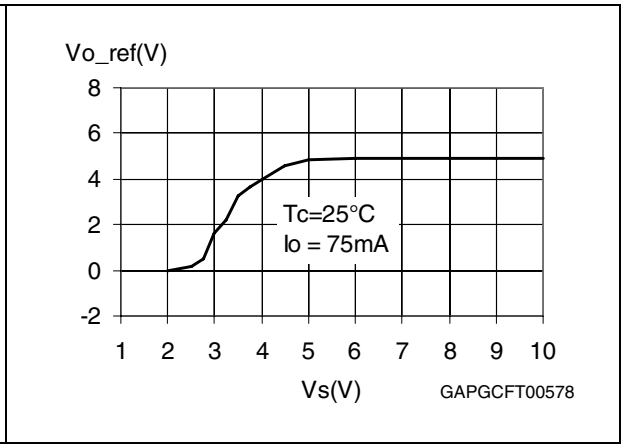


Figure 5. Output voltage vs V_{En}

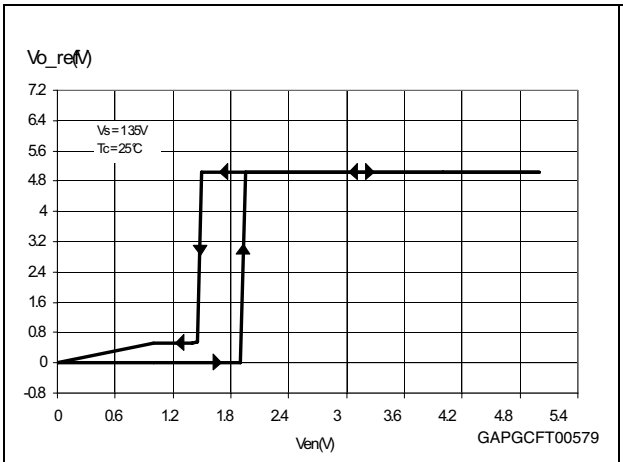


Figure 6. Drop voltage vs. output current

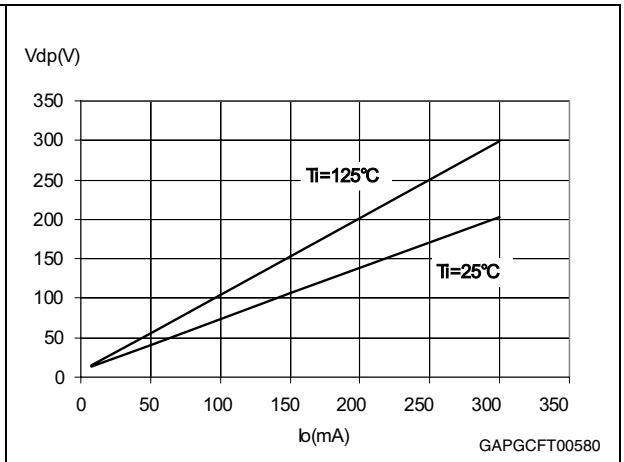


Figure 7. Current consumption vs. output current

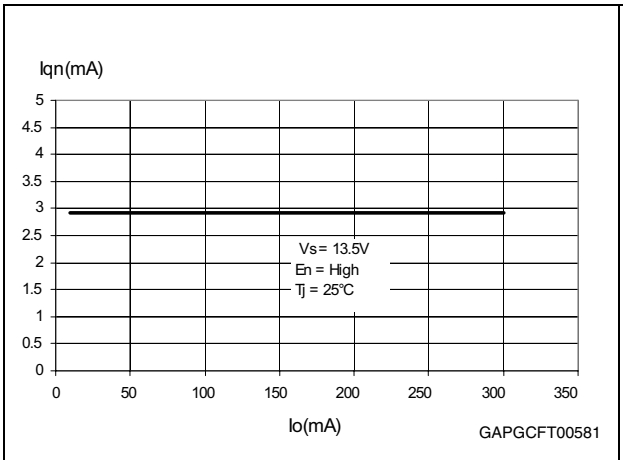


Figure 8. Current consumption vs. output current (at light load condition)

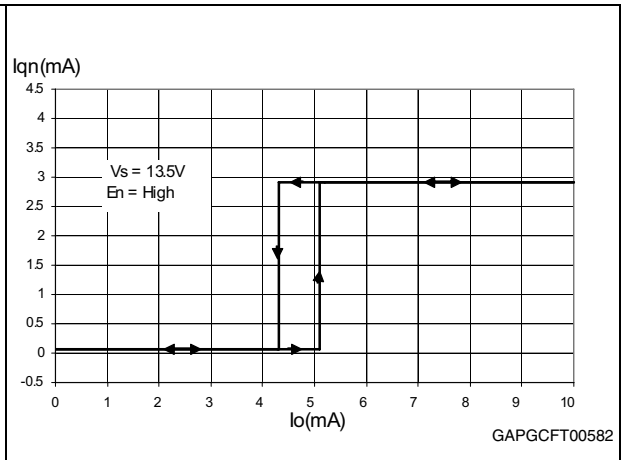


Figure 9. Current consumption vs input voltage (I_o = 0.1 mA)

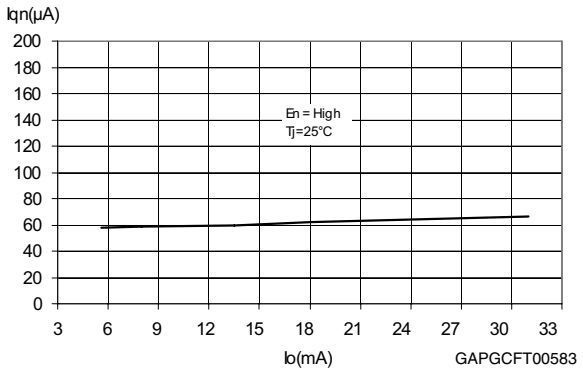


Figure 10. Current consumption vs input voltage (I_o = 100 mA)

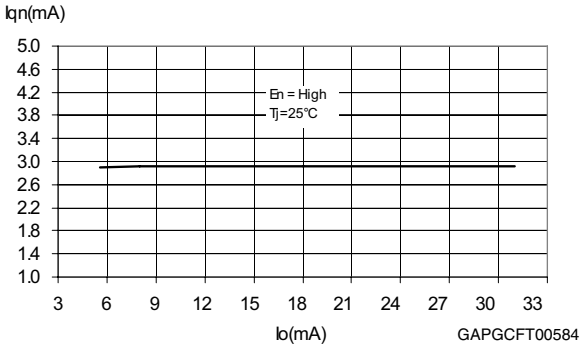


Figure 11. Current limitation vs T_j

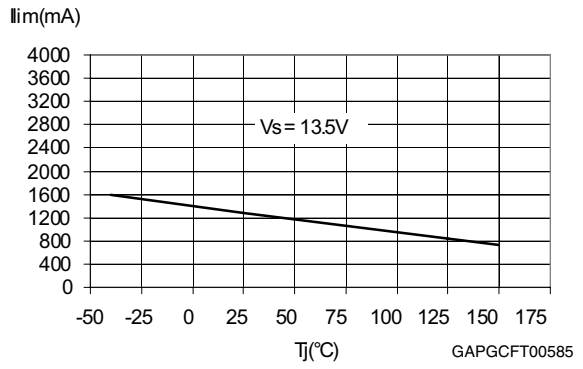


Figure 12. Current limitation vs input voltage

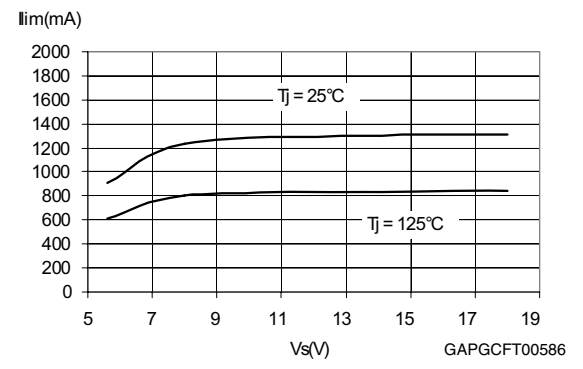


Figure 13. Short-circuit current vs T_j

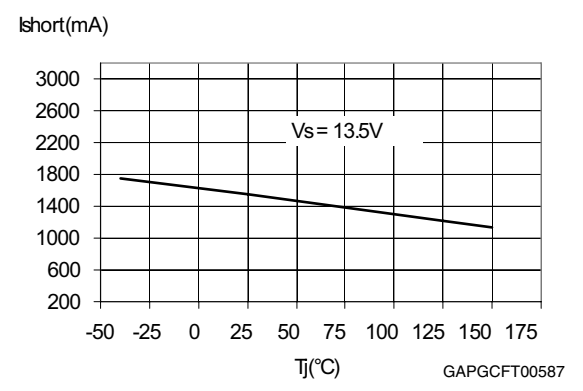


Figure 14. Short-circuit current vs input voltage

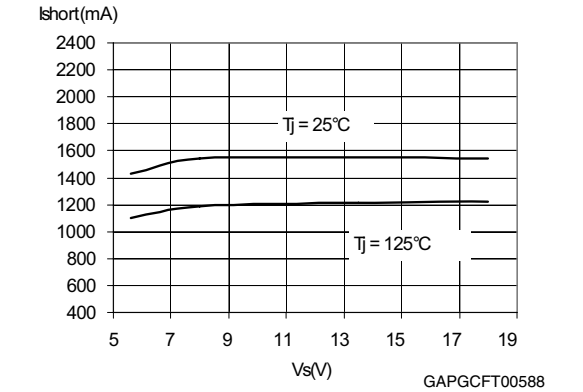


Figure 15. V_{En_high} vs T_j

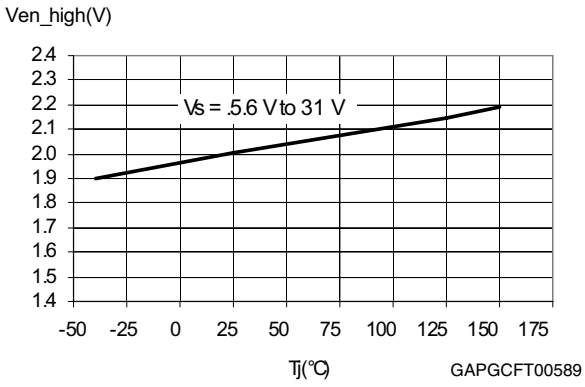


Figure 16. V_{En_low} vs T_j

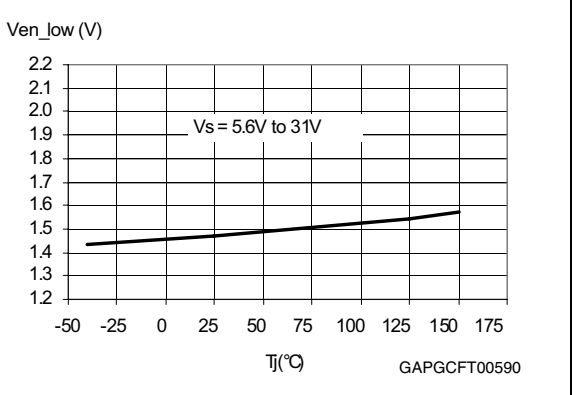


Figure 17. V_{Rhth} vs T_j

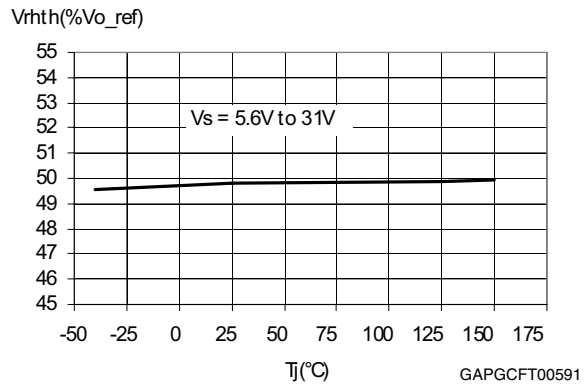


Figure 18. V_{Rlth} vs T_j

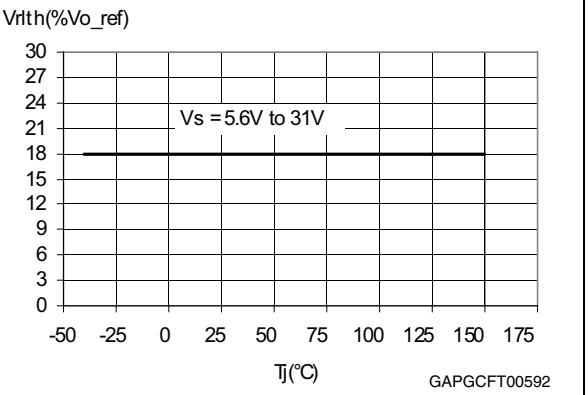


Figure 19. V_{EWi_thh} vs T_j

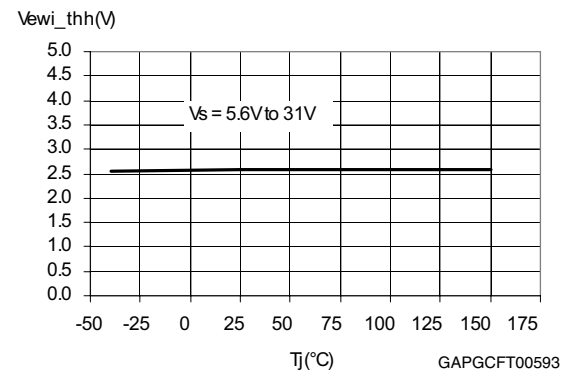


Figure 20. V_{EWi_thl} vs T_j

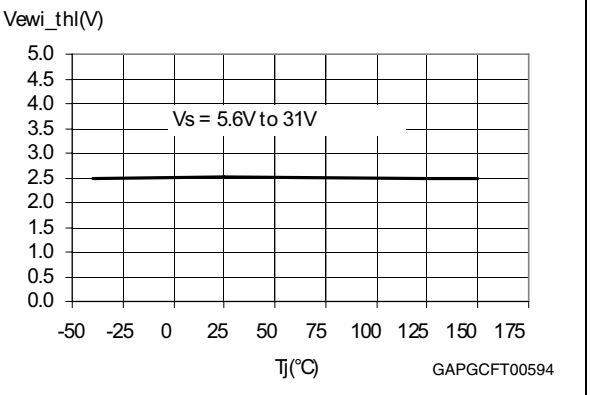


Figure 21. I_{cr} vs T_j

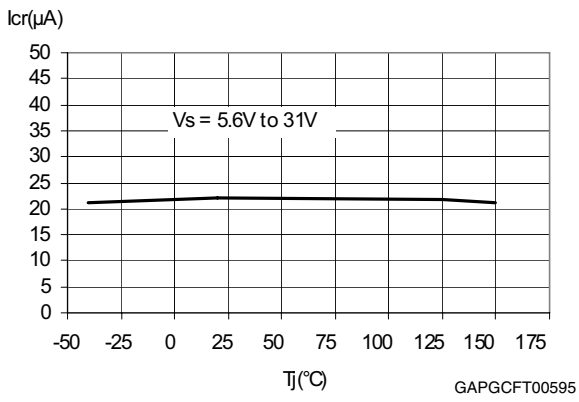
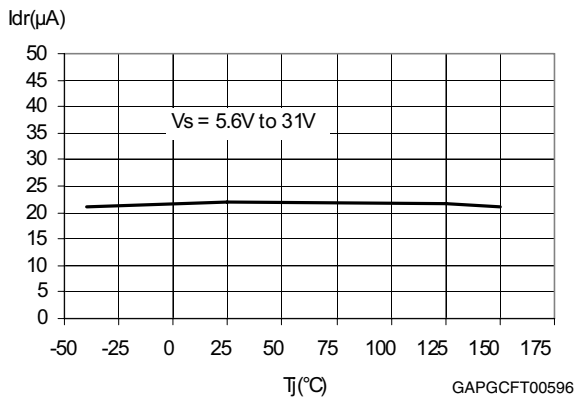


Figure 22. I_{dr} vs T_j

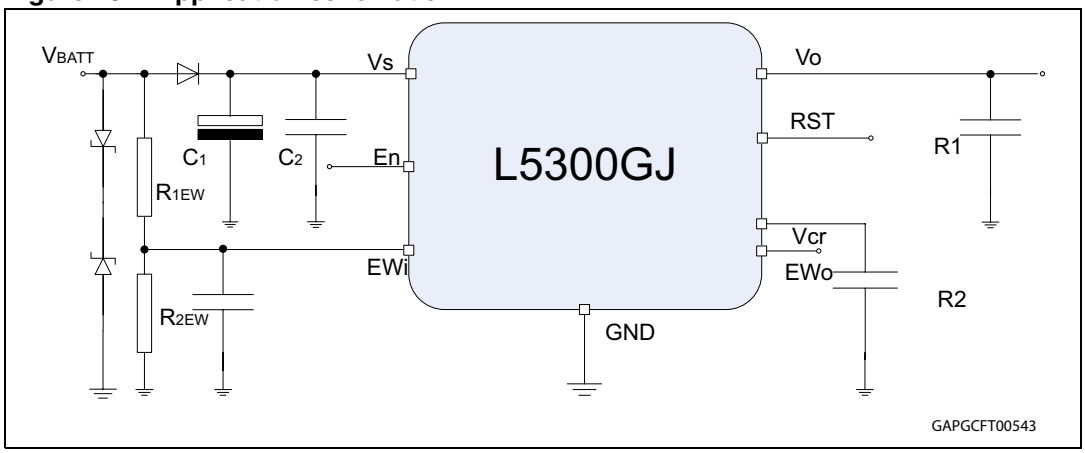


3 Application information

3.1 Voltage regulator

The voltage regulator uses a p-channel mos transistor as a regulating element. With this structure a very low dropout voltage at current up to 300 mA is obtained. The output voltage is regulated up to input supply voltage of 40 V. The high-precision of the output voltage (2%) is obtained with a pre-trimmed reference voltage. The voltage regulator automatically adapts its own quiescent current to the output current level. In light load conditions the quiescent current goes down to 55 µA only (low consumption mode). This procedure features a certain hysteresis on the output current (see *Figure 8*). Short-circuit protection to GND and a thermal shutdown are provided.

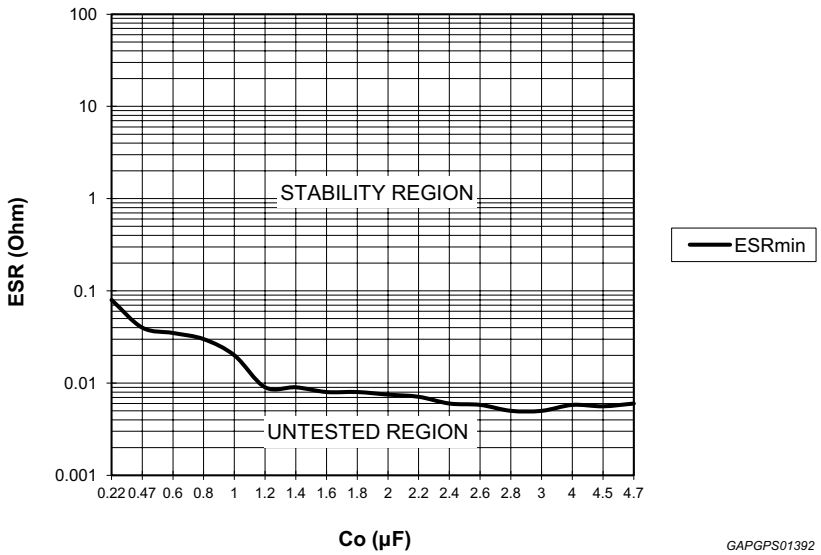
Figure 23. Application schematic



The input capacitor $C_1 \geq 100$ µF is necessary as backup supply for negative pulses which may occur on the line. The second input capacitor $C_2 \geq 220$ nF is needed when the C_1 is too distant from the V_S pin and it compensates smooth line disturbances. The C_0 ceramic capacitor, connected to the output pin, is for bypassing to GND the high-frequency noise and it guarantees stability even during sudden line and load variations. Suggested value is $C_0 = 220$ nF with ESR ≥ 100 mΩ.

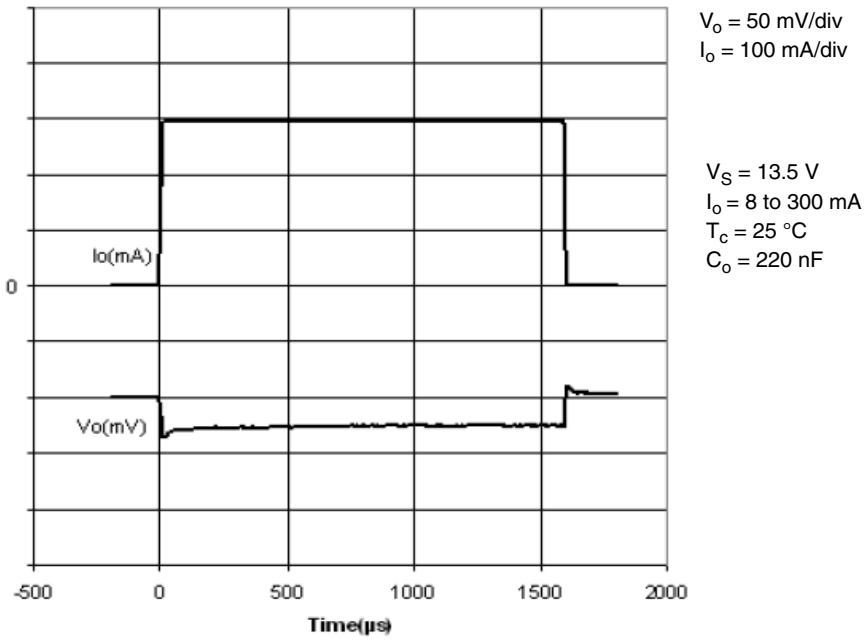
Stability region is reported in *Figure 24*.

Figure 24. Stability region



Note: The curve which describes the minimum ESR is derived from characterization data on the regulator with connected ceramic capacitors which feature low ESR values (at 100 kHz). Any capacitor with further lower ESR than the given plot value must be evaluated in each and every case.

Figure 25. Maximum load variation response



3.2 Reset

The reset circuit monitors the output voltage V_o. If the output voltage becomes lower than V_{o_th} then R_{es} goes low with a delay time (t_{rr}). When the output voltage becomes higher than V_{o_th} then R_{es} goes high with a delay time T_{rd}. This delay is obtained by 32 periods of oscillator.

The oscillator period is given by:

Equation 1

$$T_{osc} = [(V_{Rhth} - V_{Rlth}) \times C_{tr}] / I_{cr} + [(V_{Rhth} - V_{Rlth}) \times C_{tr}] / I_{dr}$$

where:

I_{cr} = 20 µA is an internally generated charge current,

I_{dr} = 20 µA is an internally generated discharge current,

V_{Rhth} = 2.5 V (typ) and **V_{Rlth}** = 0.95 V (typ) are two voltage thresholds,

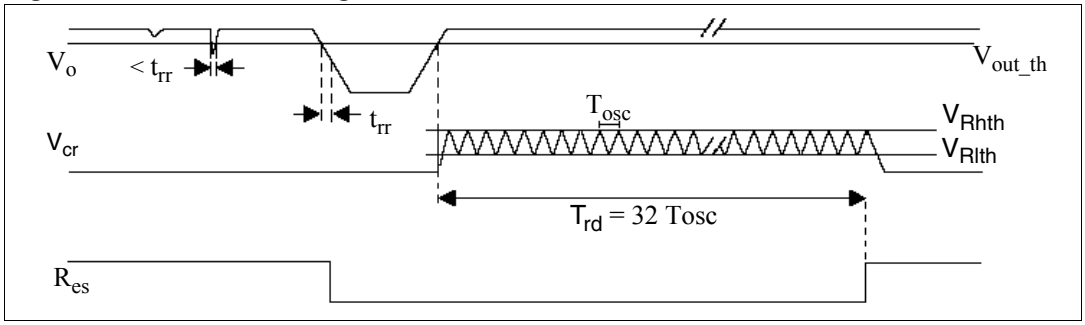
C_{tr} is an external capacitor to be put between V_{cr} pin and GND.

Reset pulse delay T_{rd} is given by:

Equation 2

$$T_{rd} = 32 \times T_{osc}$$

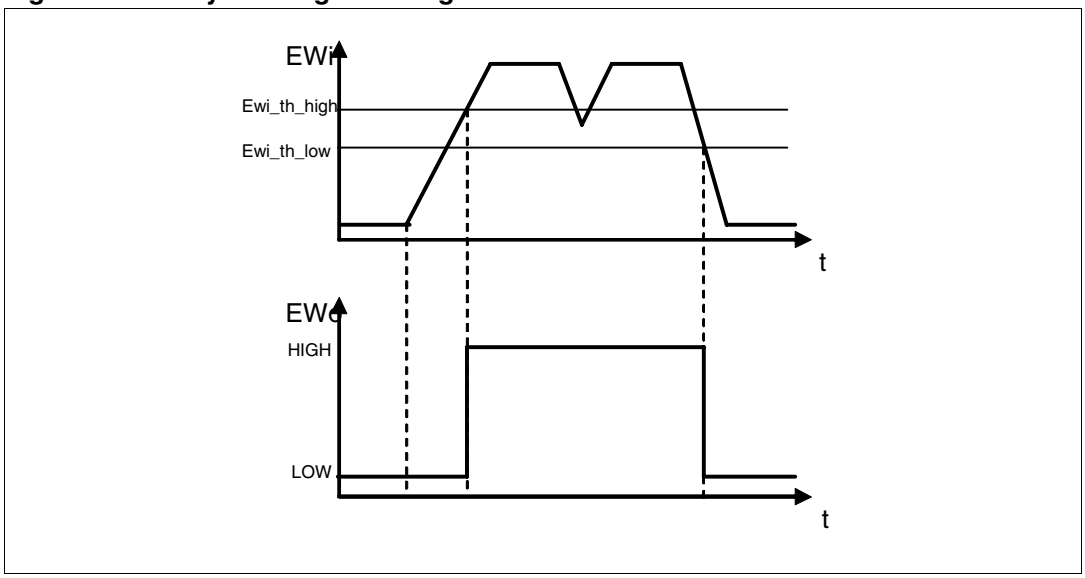
Figure 26. Reset time diagram



3.3 Early warning

This circuit compares the EW_i input signal with the internal voltage reference (typically 2.5 V). The use of an external voltage divider makes the comparator very flexible in the application. This function can be used to supervise the supply input voltage either before or after the protection diode and to give additional information to the microprocessor such as low voltage warnings.

Figure 27. Early warning time diagram

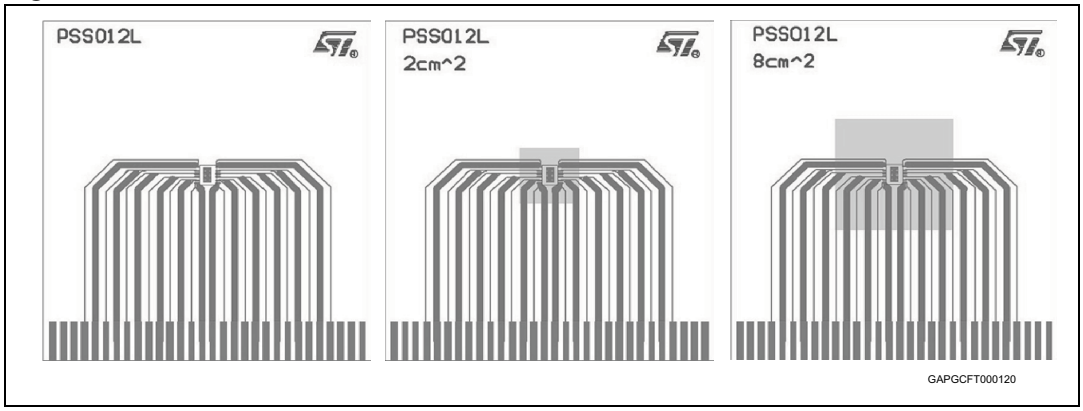


3.4 Enable

L5300GJ is also provided with an enable input, a high signal switches the regulator ON. In standby mode the output is disabled and the current consumption of the device (quiescent current) is less than 10 µA.

4 Package and PCB thermal data

Figure 28. PowerSSO-12 PC board(1)



1. Layout condition of R_{th} and Z_{th} measurements (PCB: double layer, thermal vias, FR4 area = 77 mm x 86 mm, PCB thickness = 1.6 mm, Cu thickness = 70 µm (front and back side), thermal vias separation 1.2 mm, thermal via diameter 0.3 mm +/- 0.08 mm, Cu thickness on vias 0.025 mm, Footprint dimension 4.1 mm x 6.5 mm).

Figure 29. $R_{thj\text{-}amb}$ Vs. PCB copper area in open box free air condition

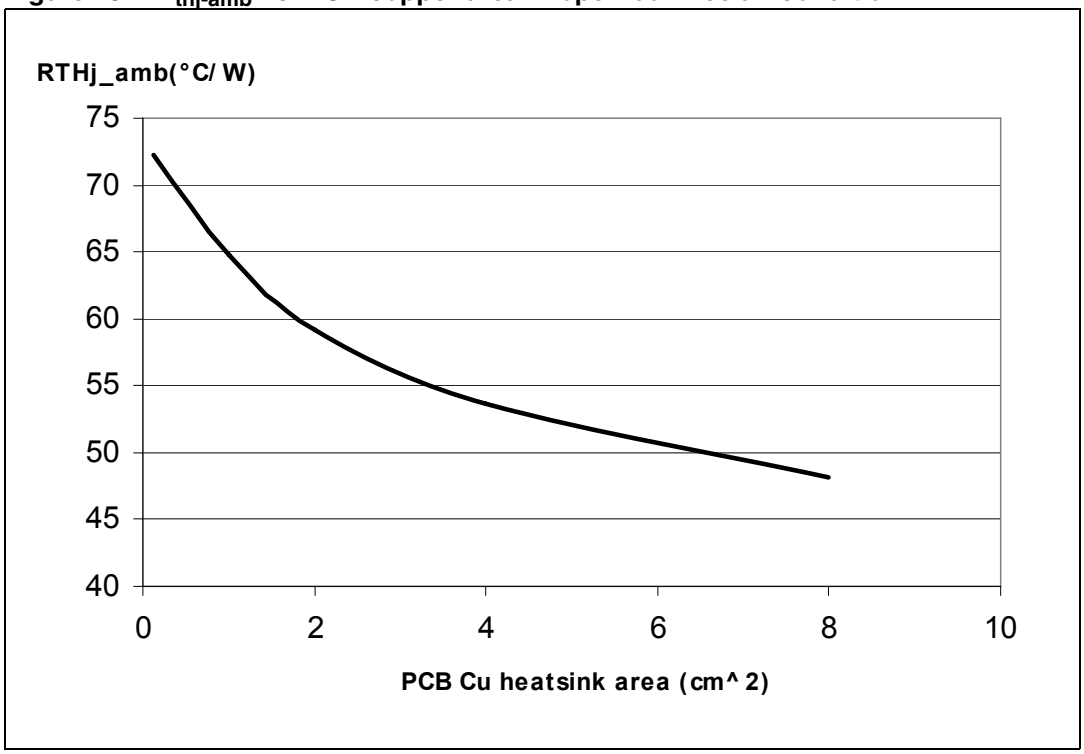
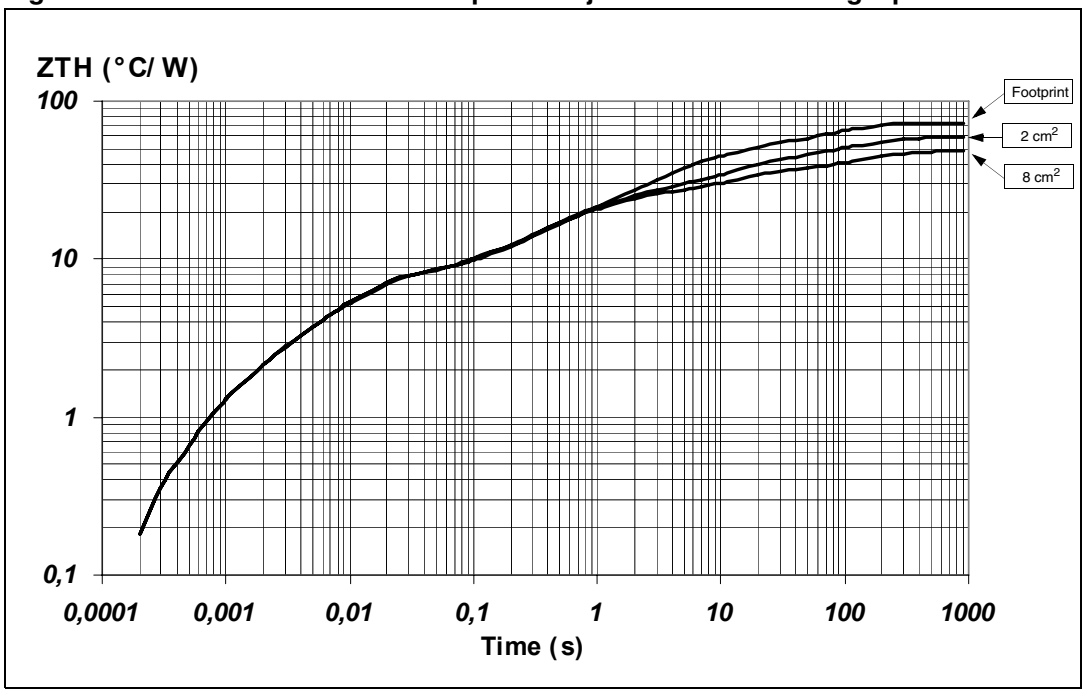


Figure 30. PowerSSO-12 thermal impedance junction ambient single pulse



Equation 3: pulse calculation formula

where $\delta = t_P/T$

Figure 31. Thermal fitting model of Vreg in in PowerSSO-12

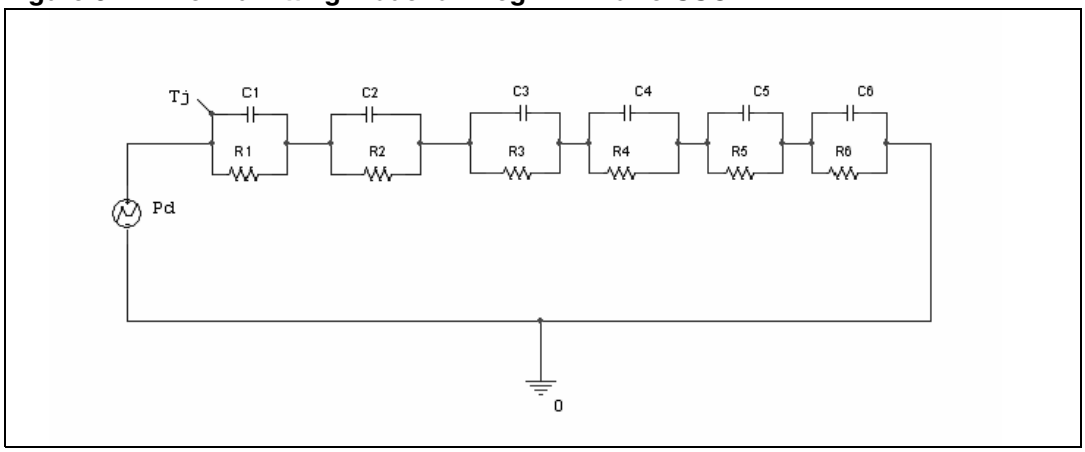


Table 9. PowerSSO-12 thermal parameter

Area (cm^2)	Footprint	2	8
R1 (°C/W)	1.2		
R2 (°C/W)	6		
R3 (°C/W)	7		
R4 (°C/W)	10	10	9
R5 (°C/W)	22	15	10
R6 (°C/W)	26	20	15
C1 (W.s/°C)	0.0008		
C2 (W.s/°C)	0.0016		
C3 (W.s/°C)	0.05		
C4 (W.s/°C)	0.2	0.1	0.1
C5 (W.s/°C)	0.27	0.8	1
C6 (W.s/°C)	3	6	9

5 Package and packing information

5.1 ECOPACK®

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

5.2 PowerSSO-12 mechanical data

Figure 32. PowerSSO-12 package dimensions

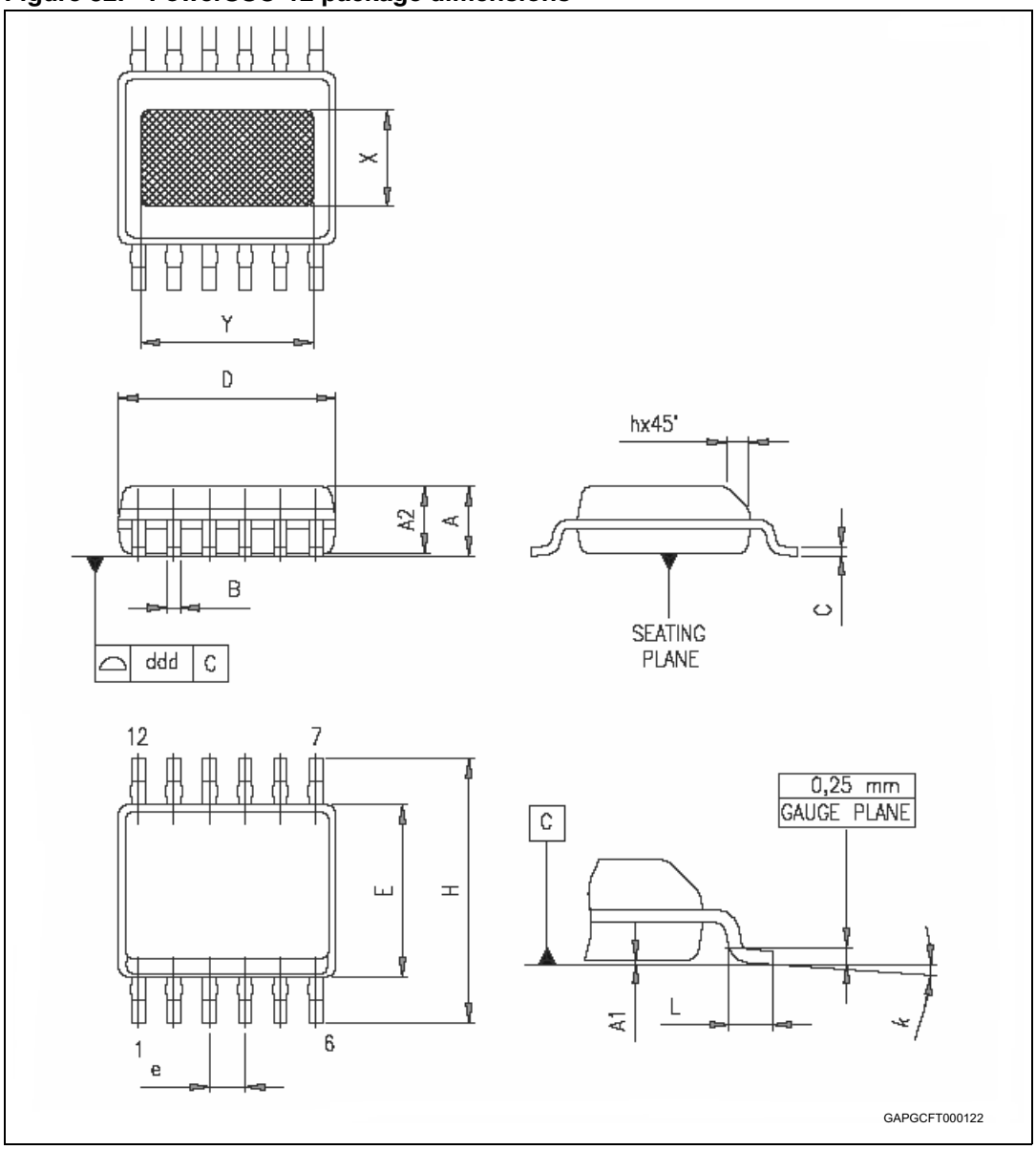
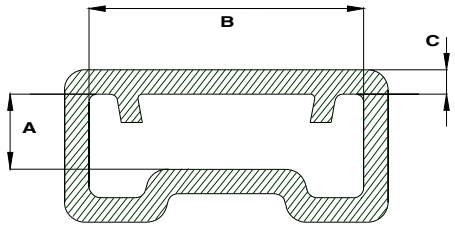


Table 10. PowerSSO-12 mechanical data

Symbol	Millimeters		
	Min.	Typ.	Max.
A	1.250		1.620
A1	0.000		0.100
A2	1.100		1.650
B	0.230		0.410
C	0.190		0.250
D	4.800		5.000
E	3.800		4.000
e		0.800	
H	5.800		6.200
h	0.250		0.500
L	0.400		1.270
k	0º		8º
X	2.200		2.800
Y	2.900		3.500
ddd			0.100

5.3 PowerSSO-12 packing information

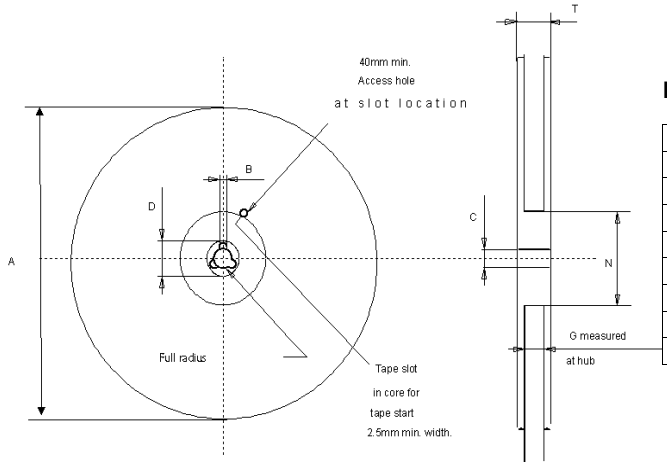
Figure 33. PowerSSO-12 tube shipment (no suffix)



Base q.ty	100
Bulk q.ty	2000
Tube length (± 0.5)	532
A	1.85
B	6.75
C (± 0.1)	0.6

All dimensions are in mm.

Figure 34. PowerSSO-12 tape and reel shipment (suffix "TR")



Reel dimensions

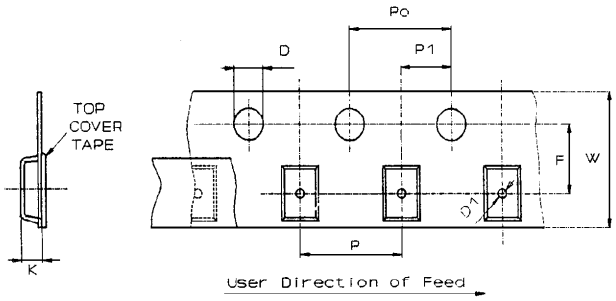
Base q.ty	2500
Bulk q.ty	2500
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	12.4
N (min)	60
T (max)	18.4

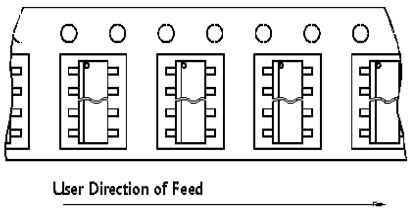
Tape dimensions

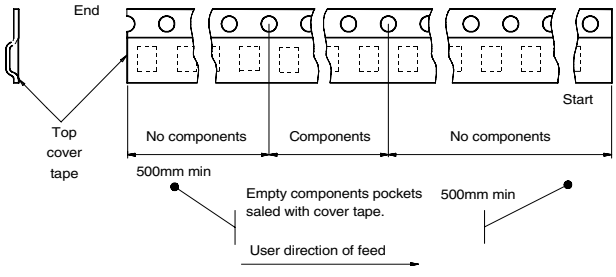
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

Tape width	W	12
Tape hole spacing	P0 (± 0.1)	4
Component spacing	P	8
Hole diameter	D (± 0.05)	1.5
Hole diameter	D1 (min)	1.5
Hole position	F (± 0.1)	5.5
Compartment depth	K (max)	4.5
Hole spacing	P1 (± 0.1)	2

All dimensions are in mm.







6 Revision history

Table 11. Document revision history

Date	Revision	Changes
09-Aug-2007	1	Initial release.
17-Sep-2008	2	Changed rev. numbering according with new “Target” standard. Updated quiescent currents on *Features* table. Updated *Description* on cover page. Changed *Figure 1: Block diagram*. Updated *Figure 2: Configuration diagram (top view)*: – added pin names. Updated *Table 2: Pins description*: – changed pin 5 from NC to V_{os} Added values to *Table 4: Thermal data*. Updated *Table 5.: General*: – updated test condition on V_{o_ref} – changed Ishort values – changed Ilim values – updated test condition on V_{line} – updated test condition on V_{load} – Inserted I_{oth_H} – Inserted I_{oth_L} – Inserted I_{oth_Hyst} Updated *Table 6: Reset*: – updated test condition on V_{res_l} – updated test condition on $V_{\mathbf{o\_th}}$ – changed V_{Rlth} values – deleted test condition on T_{rr} – changed T_{rd} values Updated *Table 7: Early warning*: – updated test condition on E_{Wo_lv} – updated test condition on I_{Wo} Updated *Table 8: Enable*: – changed typ. value on V_{En_hyst} – updated test condition on $I_{\_leak}$ Updated *Chapter 3: Application information* – deleted Figure 3: Behavior of output current versus regulated voltage V_o – updated *Section 3.2: Reset* – updated *Section 3.4: Enable* Added *Chapter 4: Package and PCB thermal data*. Updated *Table 10: PowerSSO-12 mechanical data*: – changed slug dimensions – I_o = 1 to 300 mA

Table 11. Document revision history (continued)

Date	Revision	Changes
13-Mar-2009	3	*Table 2: Pins description* – V_{os}: changed function *Table 6: Reset* – I_{Res_lkg}: deleted V_{Res} = 5 V from Test condition – V_{o_th}: deleted Io = 1 mA to 300 mA from Test condition – V_{Rlth}: changed min/typ/max values – T_{rd}: changed min/typ/max values *Section 3.2: Reset* – V_{Rlth}: changed coefficient *Section 3.4: Enable* – Replaced 5 µA with10 µA
07-Dec-2009	4	Updated corporate template (from V2 to V3) Updated features list. Updated *Figure 2: Configuration diagram (top view)* *Table 2: Pins description* – Added new row *Table 5: General* – I_{short}: changed min/typ/max value – I_{lim}: changed min/typ/max value – V_{line}: changed Test conditions – V_{load}: changed max value for Vs = 8 V to 18 V, added new row *Table 6: Reset* – V_{Rlth}: changed min/typ value *Table 8: Enable* – $I_{\_leak}$: changed typ value *Section 3.3: Early warning* – changed typical internal voltage reference value (from 1.23 V to 2.5 V) Added *Section 2.4: Electrical characteristics curves*. Updated *Chapter 3.1: Voltage regulator*.
27-Jan-2012	5	Updated *Figure 23: Application schematic* and *Figure 24: Stability region*.
07-Feb-2012	6	Modified *Figure 24: Stability region on page 16*.

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